Discrete Energy Levels in Synthesized Au Nanoparticle by Chemically Assembled Single-Electron Transistors

Shinya Kano¹,², Kosuke Maeda¹,², Daisuke Tanaka³,², Toshiharu Teranishi²,⁴, Luke W. Smith⁵, Charles G. Smith⁵, and Yutaka Majima¹,²,⁶

¹ Materials and Structures Laboratory, Tokyo Institute of Technology, 4259 Nagatsuta-cho, Midori-ku, Yokohama 226-8503, Japan
Phone: +81-45-924-5376 E-mail: kano@nanoele.msl.titech.ac.jp
² CREST, Japan Science and Technology Agency, Yokohama 226-8503, Japan
³Graduate School of Pure and Applied Sciences, University of Tsukuba, Tsukuba 305-8571, Japan
⁴Institute of Chemical Research, Kyoto University, Uji 611-0011, Japan
⁵Cavendish Laboratory, University of Cambridge, JJ Thomson Avenue, Cambridge CB3 0HE, UK
⁶Department of Printed Electronics Engineering, Sunchon National University, Sunchon 540-742, Korea

1. Introduction
Qubit defined by quantum dots has been attracting much attention because of its application for solid-state quantum information processing[1,2]. Quantum dots for qubit are classified into two important different types, self-assemble quantum dots and electrostatically defined quantum dots[1]. Measurements of discrete energy level spectra have been demonstrated in both types of quantum dots: semiconductor quantum dot[3], carbon nanomaterial[4], and metallic nanoparticles (NPs)[5]. Considering controllability and stability of device characteristics, chemically synthesized Au NPs with self-assembled monolayer (SAM) are highly useful quantum dots[6, 7]. Discrete energy level of quantum dots are expected as a two-level system of qubit.

Here, we analyzed the discrete energy level spectra of synthesized Au NP by chemically assembled single-electron transistor (SET) in detail. Synthesized Au NPs are chemically assembled as Coulomb island of SET. Spatial structure of Au NPs and electrodes are determined from the stability diagram of SET. Discrete energy level spectra of single Au NP are observed at 300 mK and mean level spacing is discussed with the theoretical value. By applying magnetic field, we observe the magnetic field evolution of discrete energy level spectra in Au NP.

2. Methods
The core diameter and standard deviation of synthesized Au NPs in SETs were 6.2 ± 0.8 nm. These Au NPs were protected by decanethiol molecules to stabilize every Au NPs. Stable SETs functionalized by SAM and Au NPs were simultaneously fabricated by the combination of the top-down and chemical bottom-up techniques[6, 7]. Initial structure of source, drain and two side-gate electrodes of Ti(2 nm)/Au(10 nm) was fabricated on a SiO₂(300 nm)/Si substrate by electron beam lithography (EBL), where the gap separation was approximately 25 nm. Nanogap electrodes were electroless-gold plated as previously reported methods and the gap separation can be controlled which is suitable for the size of Au NPs simultaneously[8]. After fabrication of the electroless-gold plated nanogap electrodes, the substrate was immersed in a 1 mM ethanolic solution of decanethiol for 24 h. Finally, the substrate was immersed in a 500 mM ethanolic solution of decanedithiol for 24 h.

The drain current – drain voltage (I_d – V_d) characteristics and drain current – gate voltage (I_d – V_g) characteristics of SETs were measured by using voltage source, digital multimeter and preamplifier. The differential conductance of drain current – drain voltage (dI/dV – V_d) were calculated by numerical differentiating the I_d – V_d curve directly without lock-in amplifiers.

Fig.1. a, Schematic structure of fabricated chemically assembled SETs. SEM image of typical electroless-gold plated electrodes is shown below. b, Stability diagram of fabricated SET at 300 mK. White broken area indicates the region of Fig.1.c. c, Stability diagram at degeneracy point of two Coulomb diamonds. White lines indicate the region of Fig.1.d. d, dI/dV – V_g characteristics at V_g = -3.3 V.

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3. Results and Discussion

Figure 1a shows a schematic structure of chemically assembled SET consisting of Au NPs and nanogap electrodes. The number of Au NPs and their position in nanogap electrodes are determined from the stability diagram of the SET. Figure 1b shows a stability diagram obtained by differential conductance ($dI/dV$) of the SET as a function of side-gate voltage ($V_g$) and $V_d$. Because two Au NPs (Au NP1 and Au NP2) are not capacitively coupled each other and work as a Coulomb island individually, two distinct rhombic-shaped Coulomb diamond are superimposed in the stability diagram. Au NP3 in Fig.1a works as a single-electron box and stability diagram.

In conclusion, we analyzed the discrete energy level spectra of synthesized Au NP by chemically assembled SET in detail. Chemically assembled SET show ideal Coulomb diamond and $dI/dV$ peaks originated from excited energy level of Au NP. Magnetic field evolution of discrete energy level spectra shows Zeeman effect and the dependence on the electron number in Au NP. These results indicate that chemically assembled qubit can be one of the candidates for solid-state quantum information processes.

4. Conclusion

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